

L Number	Hits	Search Text	DB	Time stamp
-	333	(257/207).CCLS.	USPAT; US-PGPUB	2002/11/03 12:30
-	143	(257/499).CCLS.	USPAT; US-PGPUB	2002/11/03 12:30
-	189	(257/544).CCLS.	USPAT; US-PGPUB	2002/11/03 12:31
-	718	((257/544) or (257/207) or (257/499)).CCLS.	EPO; JPO; DERWENT; IBM TDB	2002/11/03 12:31
-	1376	((257/207).CCLS.) or ((257/499).CCLS.) or ((257/544).CCLS.) or ((257/544) or (257/207) or (257/499)).CCLS.)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/11/03 12:31
-	0	((257/207).CCLS.) or ((257/499).CCLS.) or ((257/544).CCLS.) or ((257/544) or (257/207) or (257/499)).CCLS.) and strap adj cell near12 bit adj cell near12 voltage	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/11/03 12:32
-	0	((257/207).CCLS.) or ((257/499).CCLS.) or ((257/544).CCLS.) or ((257/544) or (257/207) or (257/499)).CCLS.) and strap adj cell near12 bit adj cell	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/11/03 12:32
-	0	strap adj cell near12 bit adj cell	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/11/03 12:33
-	115	strap adj cell	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/11/03 12:33
-	12	(strap adj cell) and 257/\$6.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/11/03 12:33
-	11	((strap adj cell) and 257/\$6.ccls.) and (memory adj (device or cell) or sram or rom or eprom or "eprom/flash" or dram)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/11/03 14:31
-	0	((strap adj cell) and 257/\$6.ccls.) and (memory adj (device or cell) or sram or rom or eprom or "eprom/flash" or dram) and bit adj cell and strap adj cell	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/11/03 12:38
-	4	((strap adj cell) and 257/\$6.ccls.) and (memory adj (device or cell) or sram or rom or eprom or "eprom/flash" or dram) and bit adj (line or cell) and strap adj cell	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/11/03 12:45
-	0	((strap adj cell) and 257/\$6.ccls.) and (memory adj (device or cell) or sram or rom or eprom or "eprom/flash" or dram) and bit adj (line or cell) and strap adj cell and voltage near12 body near12 strap	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/11/03 12:40
-	0	((strap adj cell) and 257/\$6.ccls.) and (memory adj (device or cell) or sram or rom or eprom or "eprom/flash" or dram) and bit adj (line or cell) and strap adj cell and voltage near15 body near15 strap	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/11/03 12:40
-	0	((strap adj cell) and 257/\$6.ccls.) and (memory adj (device or cell) or sram or rom or eprom or "eprom/flash" or dram) and bit adj (line or cell) and strap adj cell and voltage near12 strap	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/11/03 12:41

-	1	((strap adj cell) and 257/\$6.ccls.) and (memory adj (device or cell) or sram or rom or eprom or "eprom/flash" or dram) and bit adj (line or cell) and strap adj cell and voltage near12 supply	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPÄT	2002/11/03 12:45
-	4	(US-RE36837-\$ or US-6150686-\$ or US-5616961-\$ or US-5369049-\$).did.		2002/11/03 12:56
-	0	body near12 strap adj cell near12 (voltage or potential or bias or biased)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/03 12:57
-	1	strap adj cell near12 (voltage or potential or bias or biased)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/03 14:02
-	0	("999361.ap.").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/03 14:02
-	3	999361.ap.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/03 14:02
-	0	buried adj strap adj cell near12 bias	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/03 14:32
-	146	(best or buried adj strap adj cell) near12 (bias or voltage or body or offset) near12 bit	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/03 14:33
-	0	(best or buried adj strap adj cell) near12 (bias or voltage or body or offset) near12 bit adj cell	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/03 14:34
-	4	(best or buried adj strap adj cell) near12 (bias or voltage or body or offset) near12 bit adj (cell or line)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/03 14:36
-	0	(buried adj strap adj cell) near12 (bias or voltage or body or offset) near12 bit adj (cell or line)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/03 14:46
-	0	(buried adj strap) near12 (bias or voltage or body or offset) near12 bit adj (cell or line)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/03 14:39
-	0	strap adj (line or cell or row or column) near12 (bias or voltage or body or offset) near12 bit adj (cell or line or row or column)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/03 14:41
-	0	strap adj (line or cell or row or column) near12 (bias or voltage or body or offset or potential) near12 bit adj (cell or line or row or column)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/03 14:42

-	1	strap near12 (bias or voltage or body or offset or potential) near12 bit adj (cell or line or row or column)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/03 14:42
-	0	(buried adj strap adj cell) near12 bit adj (cell or line)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/03 14:46
-	16	buried adj strap near12 bit adj (cell or line)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/03 14:56
-	1	buried adj strap near12 bit adj (cell or line) and strap adj (line or cell)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/03 14:51
-	7	(US-6150686-\$ or US-RE36837-\$ or US-4724190-\$ or US-6455886-\$ or US-5616961-\$ or US-5369049-\$).did. or (US-20020080676-\$).did.	USPAT; US-PGPUB	2002/12/01 17:23
-	0	bit adj line and word adj line and dummy adj cell and body near12 (potential or voltage) and sram.ti,ab,clm. and leakage.ti,ab,clm.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/01 17:25
-	895	bit adj line and word adj line and dummy adj cell	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/01 17:25
-	7	bit adj line and word adj line and dummy adj cell near12 body and (leakage or leaking or leak)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/01 18:25
-	1561	((257/204) or (257/205) or (257/206) or (257/207)).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/01 18:25
-	4	((257/204) or (257/205) or (257/206) or (257/207)).CCLS.) and (bit-line or bit adj line or bitline) near12 dummy	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/01 18:55
-	1	((257/204) or (257/205) or (257/206) or (257/207)).CCLS.) and (strap adj cell or dummy adj cell) and gate adj array	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/01 19:30
-	2	((257/204) or (257/205) or (257/206) or (257/207)).CCLS.) and (strap adj cell or dummy adj cell) and (leakage or leaking or leak)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/01 19:35
-	15	(strap adj cell or dummy adj cell) near15 body and (leakage or leaking or leak)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/01 19:36
-	92	(body adj bias or body adj strap or body adj contact) and memory.ti,ab,clm. and 257/\$6.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/11 09:33

-	73	(body adj bias or body adj strap or body adj contact) and memory.ti,ab,clm. and 257/\$6.ccls. and (bit adj line or bitline or bit-line)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/11 09:34
-	21	(body adj bias or body adj strap or body adj contact) same (bitline or bit-line or bit adj line) and memory.ti,ab,clm. and 257/\$6.ccls.	USPAT; US-PGPUB	2002/12/11 09:36
-	0	(body adj bias or body adj strap or body adj contact) near15 (bitline or bit-line or bit adj line) and memory.ti,ab,clm. and 257/\$6.ccls.	EPO; JPO; DERWENT; IBM_TDB	2002/12/11 09:36
-	1	(body adj bias or body adj strap or body adj contact) near15 (bitline or bit-line or bit adj line) and memory.ti,ab,clm.	EPO; JPO; DERWENT; IBM_TDB	2002/12/11 09:37
-	1	((body adj bias or body adj strap or body adj contact) same (bitline or bit-line or bit adj line) and memory.ti,ab,clm. and 257/\$6.ccls.) or ((body adj bias or body adj strap or body adj contact) near15 (bitline or bit-line or bit adj line) and memory.ti,ab,clm.)	EPO; JPO; DERWENT; IBM_TDB	2002/12/11 09:37
-	22	((body adj bias or body adj strap or body adj contact) same (bitline or bit-line or bit adj line) and memory.ti,ab,clm. and 257/\$6.ccls.) or ((body adj bias or body adj strap or body adj contact) near15 (bitline or bit-line or bit adj line) and memory.ti,ab,clm.)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/11 10:45
-	2	("6018172").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/11 09:56
-	0	((body adj bias or body adj strap or body adj contact) same (bitline or bit-line or bit adj line) and memory.ti,ab,clm. and 257/\$6.ccls.) or ((body adj bias or body adj strap or body adj contact) near15 (bitline or bit-line or bit adj line) and memory.ti,ab,clm.)) and leakage.ti,ab,clm.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/11 10:46
-	14	((body adj bias or body adj strap or body adj contact) same (bitline or bit-line or bit adj line) and memory.ti,ab,clm. and 257/\$6.ccls.) or ((body adj bias or body adj strap or body adj contact) near15 (bitline or bit-line or bit adj line) and memory.ti,ab,clm.)) and leakage	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/11 10:46
-	8	((body adj bias or body adj strap or body adj contact) same (bitline or bit-line or bit adj line) and memory.ti,ab,clm. and 257/\$6.ccls.) or ((body adj bias or body adj strap or body adj contact) near15 (bitline or bit-line or bit adj line) and memory.ti,ab,clm.)) and leakage adj current	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/11 15:14
-	15	((body adj bias or body adj strap or body adj contact) same (bitline or bit-line or bit adj line) and memory.ti,ab,clm. and 257/\$6.ccls.) or ((body adj bias or body adj strap or body adj contact) near15 (bitline or bit-line or bit adj line) and memory.ti,ab,clm.)) and leakage adj current and cmos	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/11 15:44

-	0	((body adj bias or body adj strap or body adj contact) same (bitline or bit-line or bit adj line) and memory.ti,ab,clm. and 257/\$6.ccls.) or ((body adj bias or body adj strap or body adj contact) near15 (bitline or bit-line or bit adj line) and memory.ti,ab,clm.)) and leakage adj current and cmos.ti,ab,clm.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/11 15:36
-	1	(body adj bias or body adj strap or body adj contact) same (bitline or bit-line or bit adj line) and memory.ti,ab,clm. and (365/\$6.ccls. or 257/\$6.ccls.) and leakage adj current and cmos.ti,ab,clm.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/11 16:58
-	1	(cmos or cmosfet).ti,ab,clm. and (body adj contact or body adj strap or body adj bias) near12 (separate or each or both) near12 (NMOS or PMOS or n-channel or p-channel or NMOSFET or PMOSFET)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/11 17:02
-	1	(cmos or cmosfet).ti,ab,clm. and (body adj contact or body adj strap or body adj bias) near12 (separate or each or both) near12 (NMOS or PMOS or n-channel or p-channel or NMOSFET or PMOSFET)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/11 17:05
-	10	(cmos or cmosfet) and (body adj contact or body adj strap or body adj bias) near12 (separate or each or both) near12 (NMOS or PMOS or n-channel or p-channel or NMOSFET or PMOSFET)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/11 17:17
-	49	(cmos or cmosfet) and (body adj contact or body adj strap or body adj bias or body adj fixing or body adj potential) same (separate or each or both) same (NMOS or PMOS or n-channel or p-channel or NMOSFET or PMOSFET)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/11 18:28
-	19	(cmos or cmosfet) and (body adj contact or body adj strap or body adj bias or body adj fixing or body adj potential) same (separate or each or both) same (NMOS or PMOS or n-channel or p-channel or NMOSFET or PMOSFET) same leakage	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/11 18:34
-	20	(cmos or cmosfet) and (body adj node or body adj contact or body adj strap or body adj bias or body adj fixing or body adj potential) same (separate or each or both) same (NMOS or PMOS or n-channel or p-channel or NMOSFET or PMOSFET) same leakage	USPAT; US-PGPUB	2002/12/11 18:35